Diode Semiconductor Device - Page 1 of 1



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| Incl  | osure Material:                                    |
|-------|--|
| Met   | al   |
| Ove   | erall Length:                                      |
| 0.40  | 09 inches  |
| Ter   | minal Length:                                      |
| 0.18  | 35 inches  |
| Ove   | erall Diameter:                                    |
| 0.24  | 10 inches  |
| Μοι   | unting Method:                                     |
| Terr  | minal  |
| Fea   | tures Provided:                                    |
| Her   | metically sealed case                              |
| Sen   | niconductor Material:                              |
| Silic | con  |
| Vol   | tage Rating In Volts Per Characteristic:           |
| 60.0  | ) regulator voltage                                |
| Cur   | rent Rating Per Characteristic:                    |
| 10.0  | 00 milliamperes repetitive peak forward current    |
| Max   | kimum Operating Tempurature Per Measurement Point: |
| 500   | .0 degrees celsius junction                        |
| Ter   | minal Type And Quantity:                           |
| 2 pi  | n  |
| She   | If Life:   |
| N/a   |  |
| Uni   | t Of Measure:                                      |
|       |  |
| Den   | nilitarization:                                    |
| No    |  |
| Fiig  | :  |
| A11   | 0a0  |